

Centro Nacional de Microelectrónica (CNM)

Instituto de Microelectrónica de Barcelona(IMB)



IMB-CNM Presentation

- ❑ **Centro Nacional de Microelectrónica**
- ❑ **Public Research Institute (CSIC)**
- ❑ **Located in Bellaterra, close to Barcelona (Spain)**
- ❑ **Devoted to Nano and Microelectronics**
- ❑ **Micro Nano Fabrication Facility (Clean Room)**



- ❑ **Departments:**
 - **Micro and Nano Systems**
 - ❑ Silicon sensors and actuators
 - ❑ Nanotechnologies
 - **Systems Integration**
 - ❑ Power devices
 - ❑ Circuits and systems design
 - ❑ Biomedical applications



IMB-CNM facilities

□ Clean Room

- 1.500 m², class 100 to 10.000
- Micro and nano fabrication technologies
- Three areas:
 - Pure (CMOS)
 - Noble metals allowed
 - Nanoelectronics

□ Processes

- 4" complete
- 6" partial (no full thermal processes)

□ Available technologies:

- CMOS, BiCMOS, MCM-D, MEMS/NEMS, power devices
- Bump bonding packaging

□ Silicon micromachining

□ Packaging

- 200 m², class 100

□ Laboratories

- Characterization and test
 - DC and RF (up to 8 GHz)
 - Wafer testing
 - Thermography
 - Radiation testing
- Reverse Engineering
- Simulation
- CAD
- Mechanical Workshop
- Chemical sensors
- Bio-sensors
- Radiation sensors
- Optical sensors



Radiation Detectors group

□ People

- 6 permanent doctors
- 2 contracted doctors
- 4 PhD students
- 2 Engineer

□ Activities started in 1996

□ Experiments

- Members of the RD50 CERN Collaboration
- ATLAS, ATLAS upgrade (sLHC)
- GRI (Gamma Radiation Imager)



- ▣ **Contributions to Particle Physics – CERN**
- ▣ **Security**
- ▣ **Medical**
- ▣ **Space**

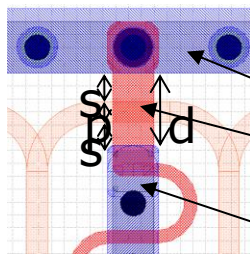
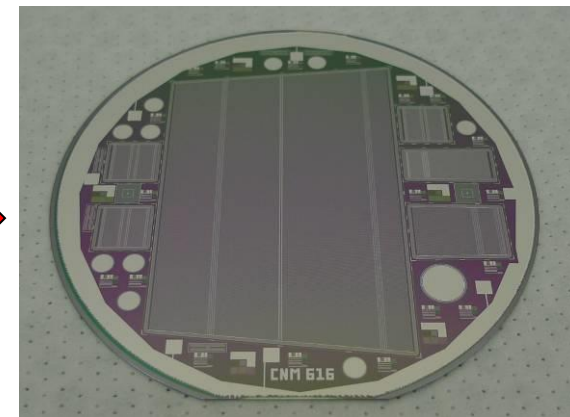
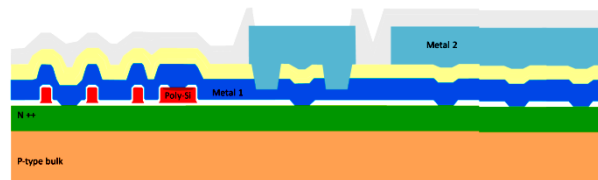
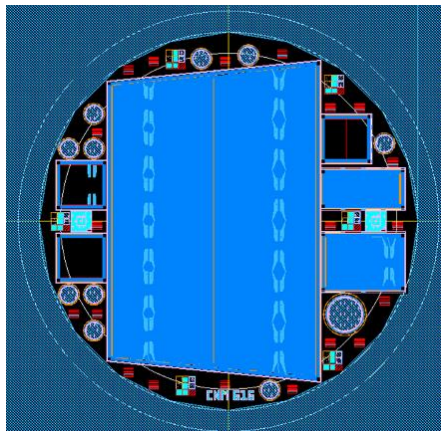
- > **LabRad**
- > **Flip Chip**
- > **3D Printer**

Application Oriented

Particle Physics– Strip detectors

□ Design, fabrication and optimization

- Design and fabrication of full ATLAS-like sensors
- Fabrication of sensors for the ATLAS Upgrade End Cap prototypes
- Fabrication of sensors for the RD50 Collaboration



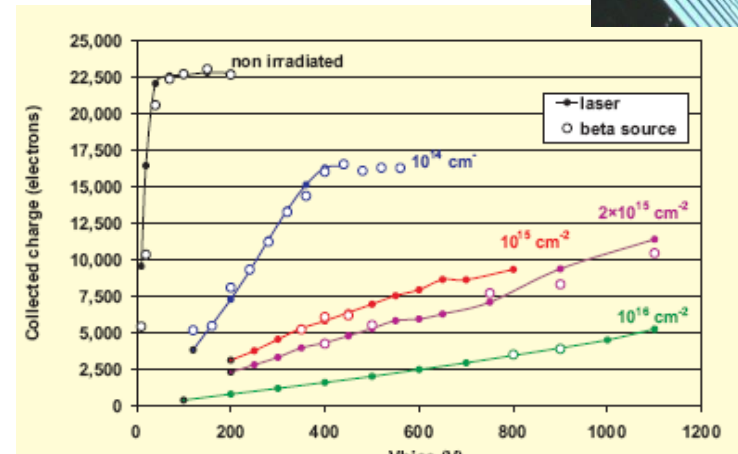
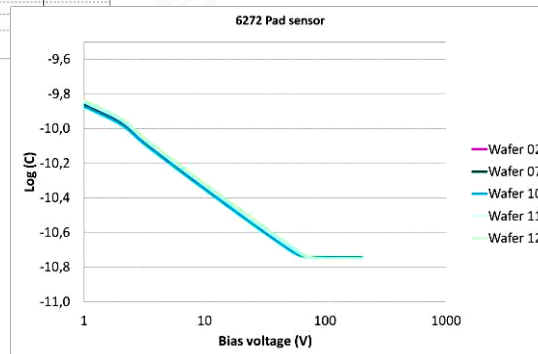
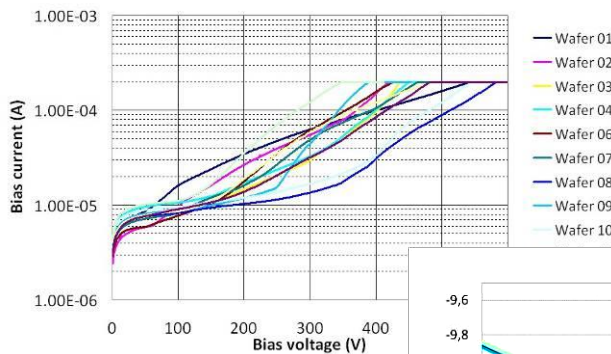
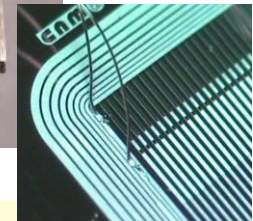
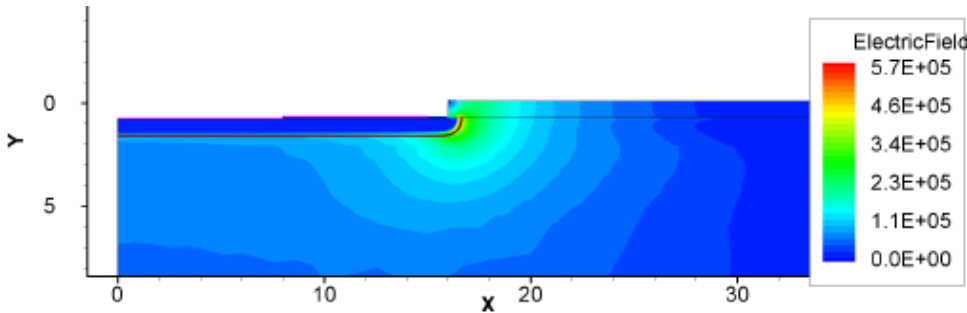
Bias rail
 Polysilicon
 "bridge/gate"
 Implant

Optimization



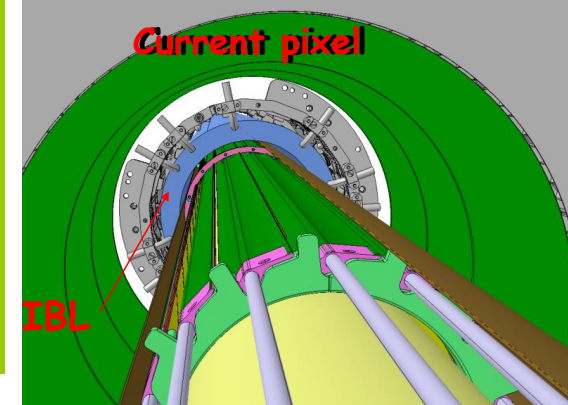
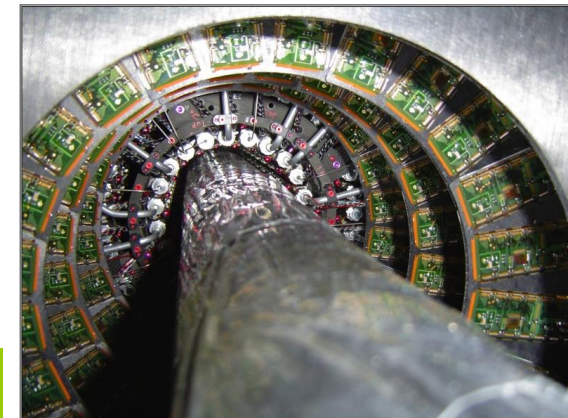
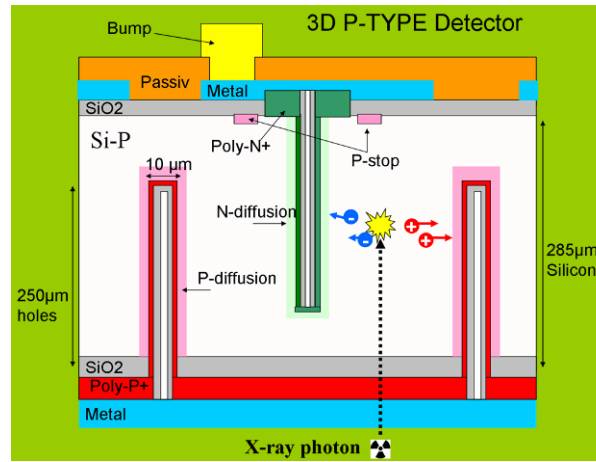
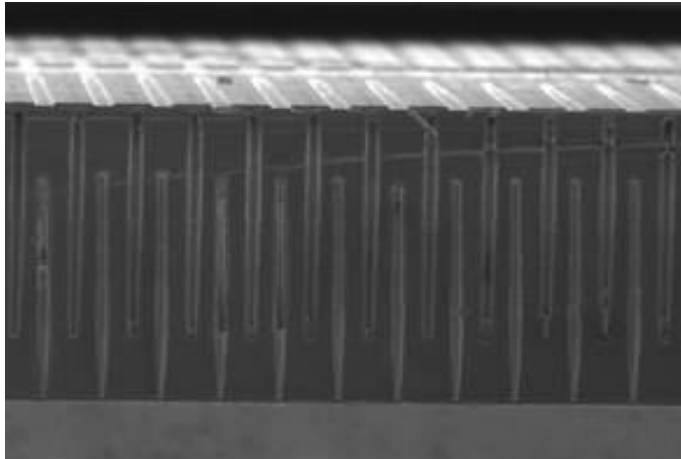
Particle Physics – Strip detectors

Simulation, characterization, irradiation



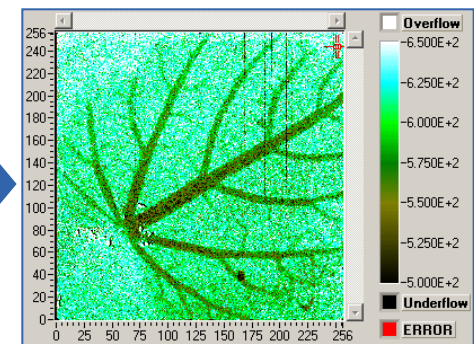
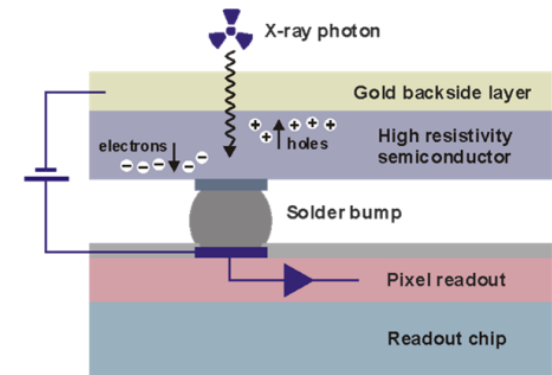
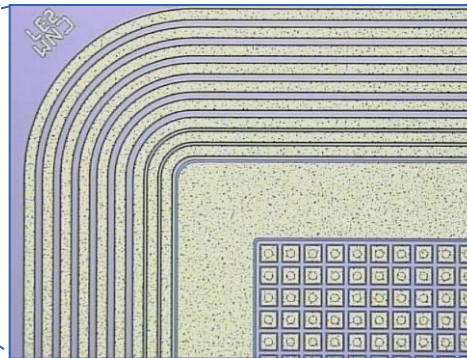
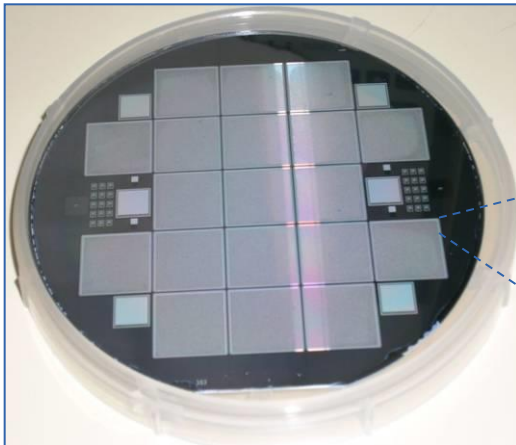
Particle Physics – 3D detectors

- Development and construction of pixel detectors for the IBL and ATLAS Upgrade experiment
- Fabrication of 72 wafers/year between 2011 y 2012



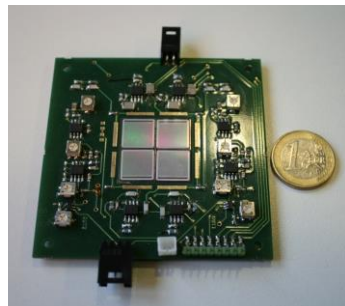
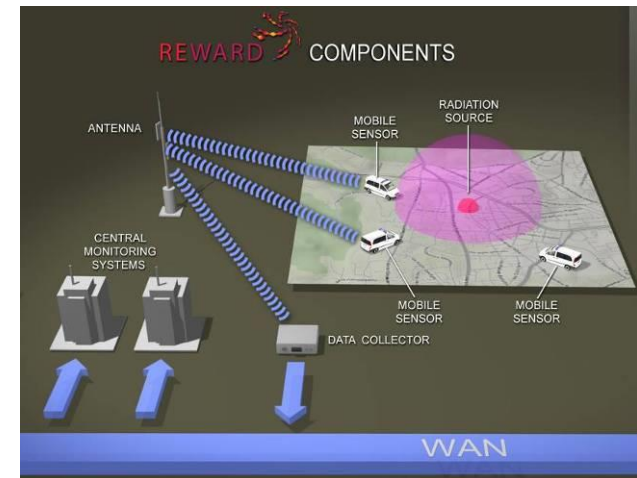
Particle Physics – Pixel detectors

- ❑ Fabrication of pixel detectors in silicon
- ❑ CdTe detectors processing
- ❑ Bump bonding technology
- ❑ High density Flip-chip



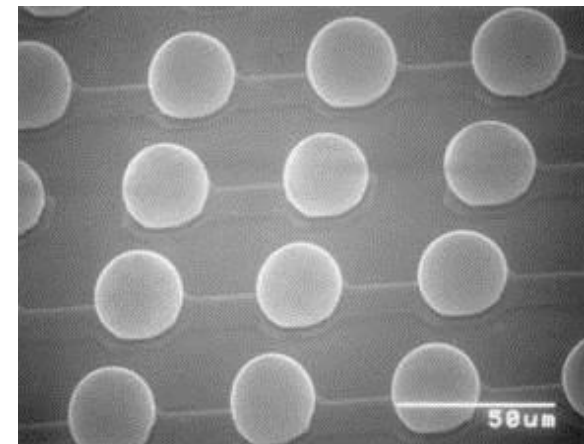
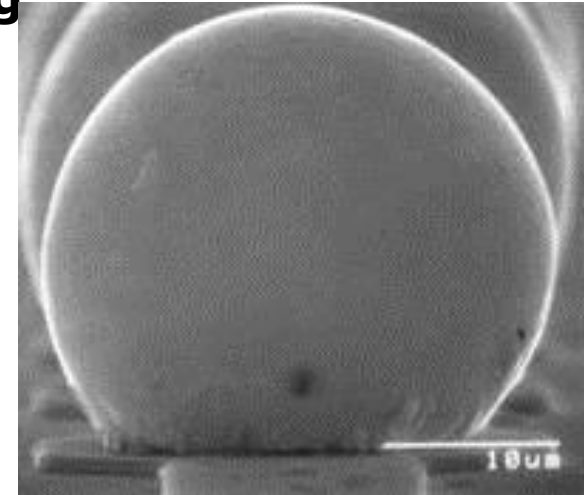
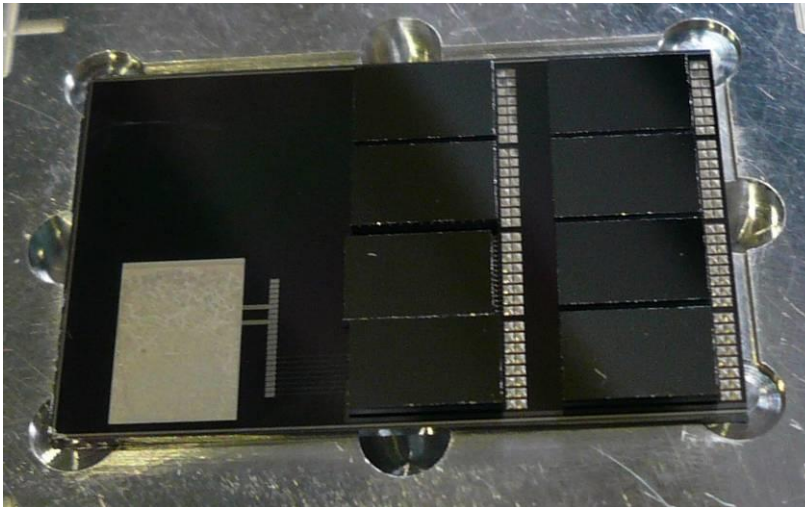
Security –REWARD Project

- ❑ **Vehicle-borne autonomous units to detect radiation**
- ❑ **Radiation detectors for neutrons (Si) and gammas (CZT)**
- ❑ **Radioactive isotopes determination**
- ❑ **GPS localisation**
- ❑ **Secured communications(TETRA)**
- ❑ **Real-time processing data in a control center**
- ❑ **Objetive: to determine a radioactive area in real time**



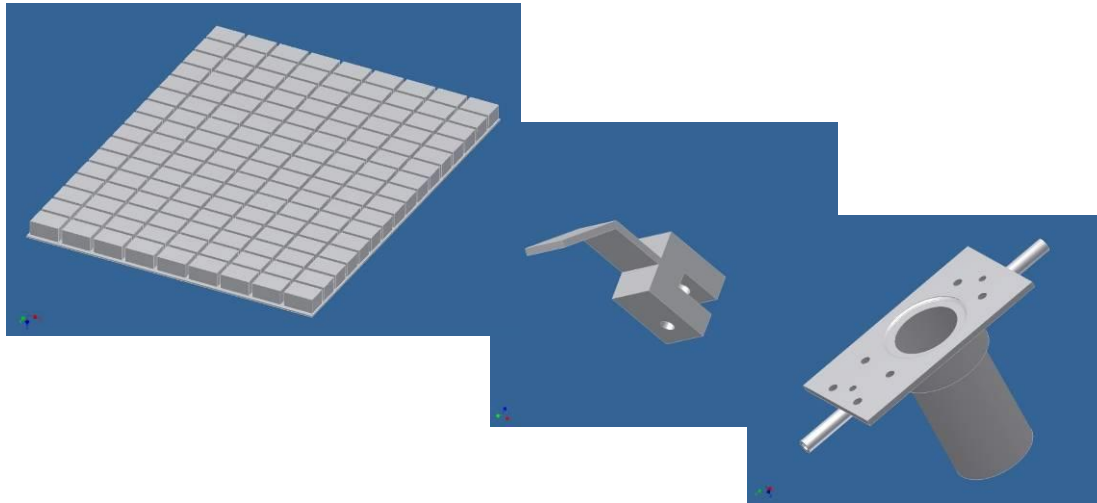
Flipchip Packaging

- ❑ Sn/Ag and Sn/Pb bump electroplating
- ❑ TiW/Cu electroplated UBM
- ❑ Ni/Au electroless UBM
- ❑ SET FC150 Pick&Place
- ❑ 1 micron placing accuracy
- ❑ Reflow in formic acid



3D Rapid Manufacturing

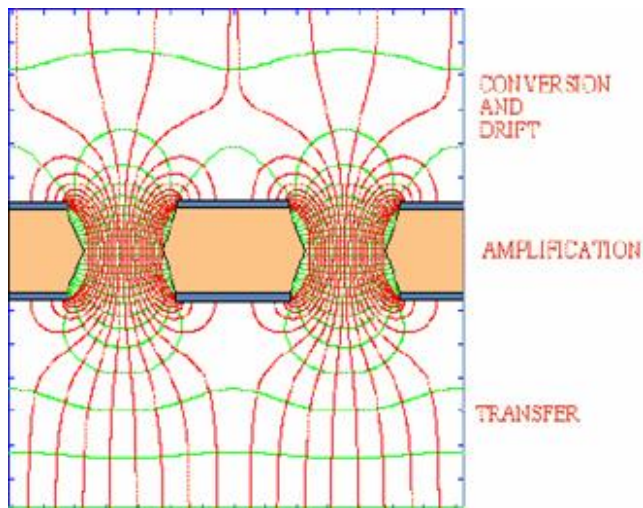
- ❑ **Polyamide Laser-sintering system**
- ❑ **EOS FORMIGA P 100**
- ❑ **From CAD to piece in few hours**
 - **Effective building volume:
20 cm x 25 cm x 33 cm**
 - **Resolution ~ 0.1 mm (vertical)**



Medical Applications– GEM Detectors

- National funding for developing GEM detectors
- 3-year project in collaboration with IFAE and HIP (observer)

 This is the reason to apply for CNM's membership into RD51 collaboration



GEM

